



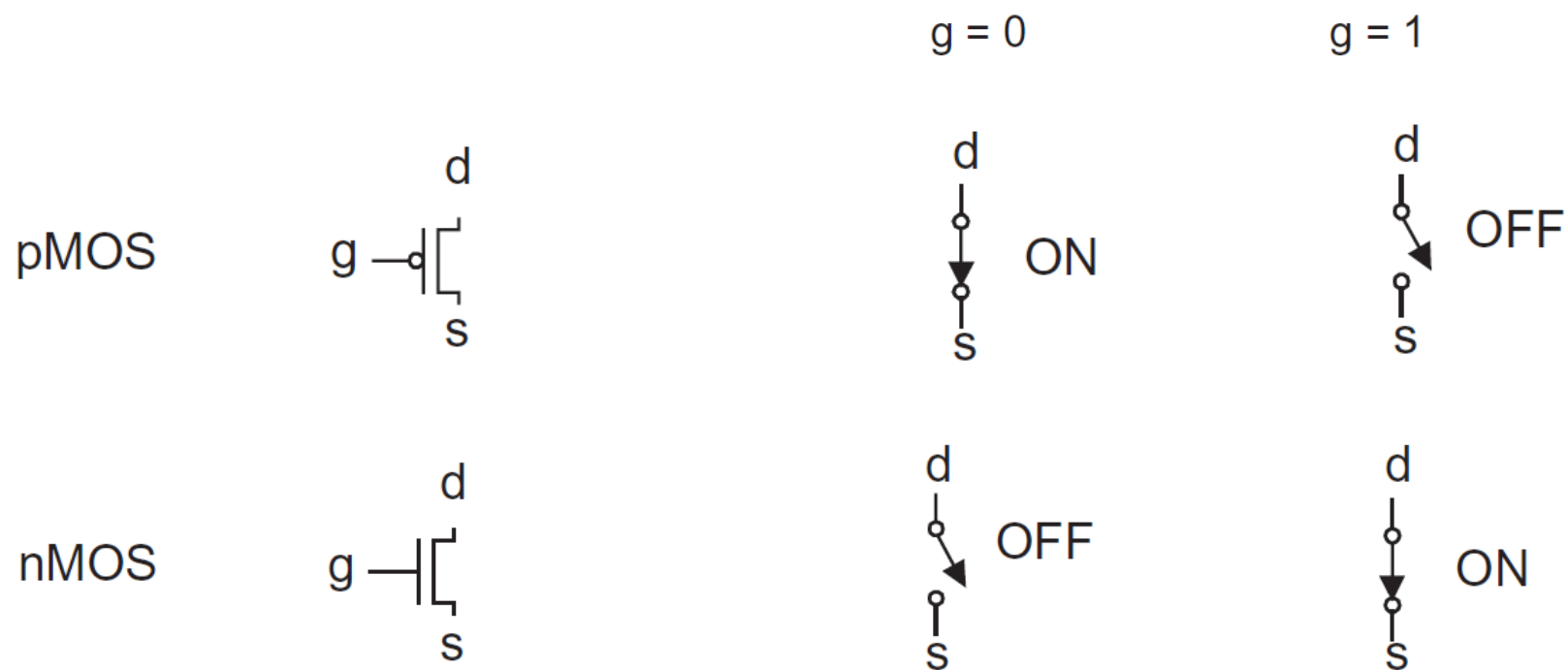
Полеви транзистор

MOSFET - metal-oxide-semiconductor field-effect transistor

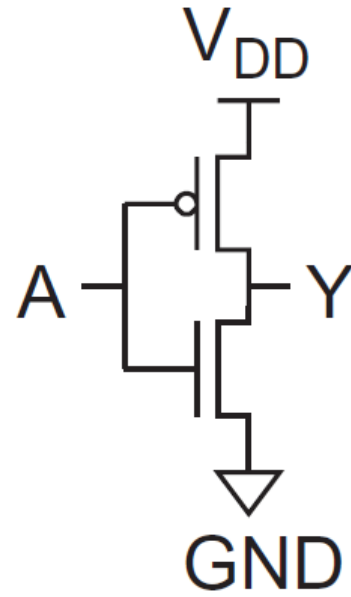
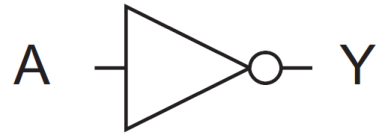
Тема: MOSFET-и в действие – логически схеми

Основата на всеки съвременен компютърен чип е CMOS логиката, което е съкращение от Complementary Metal-Oxide-Semiconductor

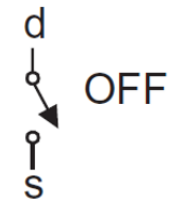
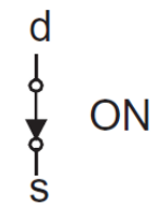
„Комплиментарен“ означава, че използва два вида MOSFET елементи, работещи заедно като перфектна push-pull двойка: N-канален MOSFET и P-канален MOSFET.



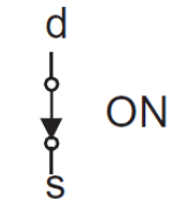
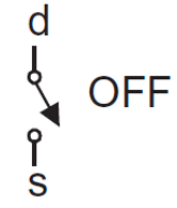
CMOS Inverter



$g = 0$

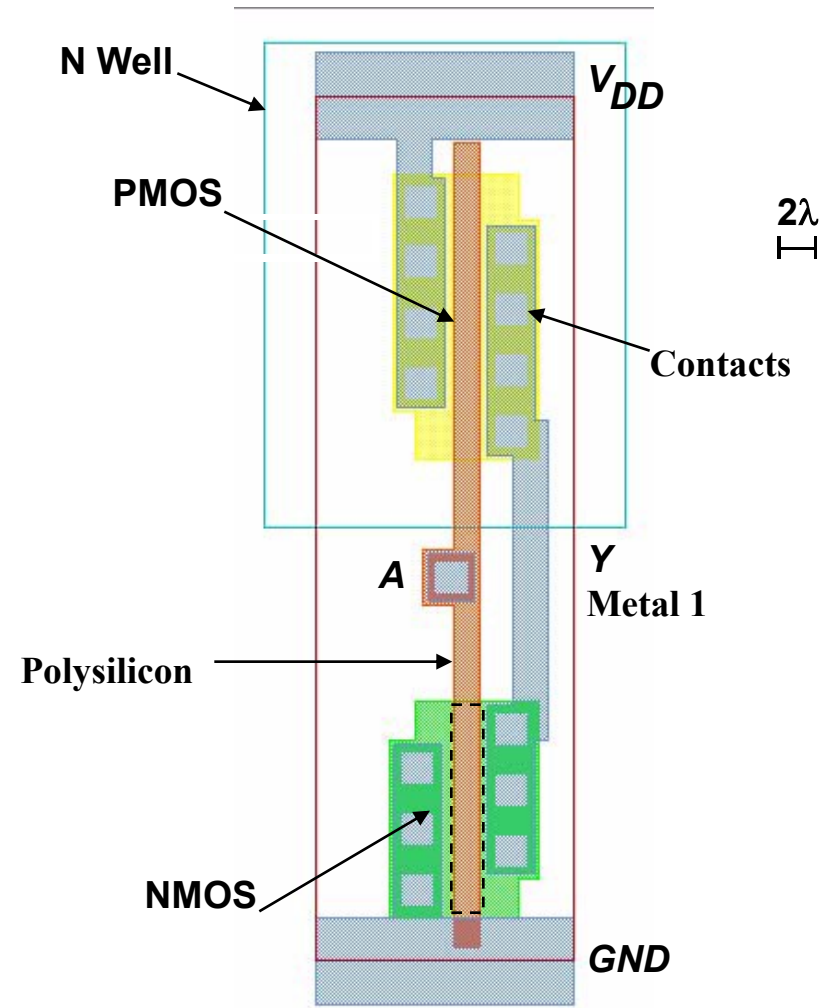
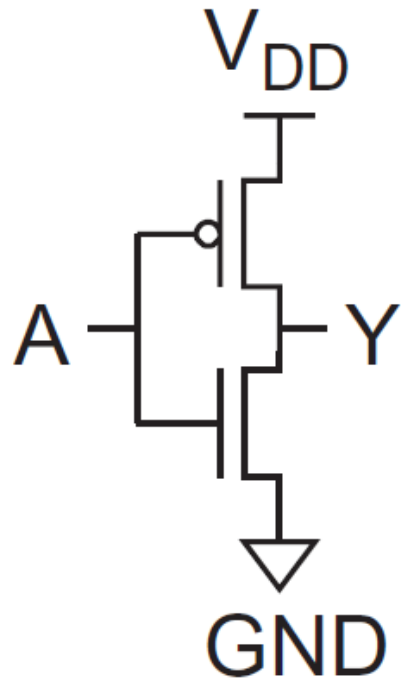


$g = 1$

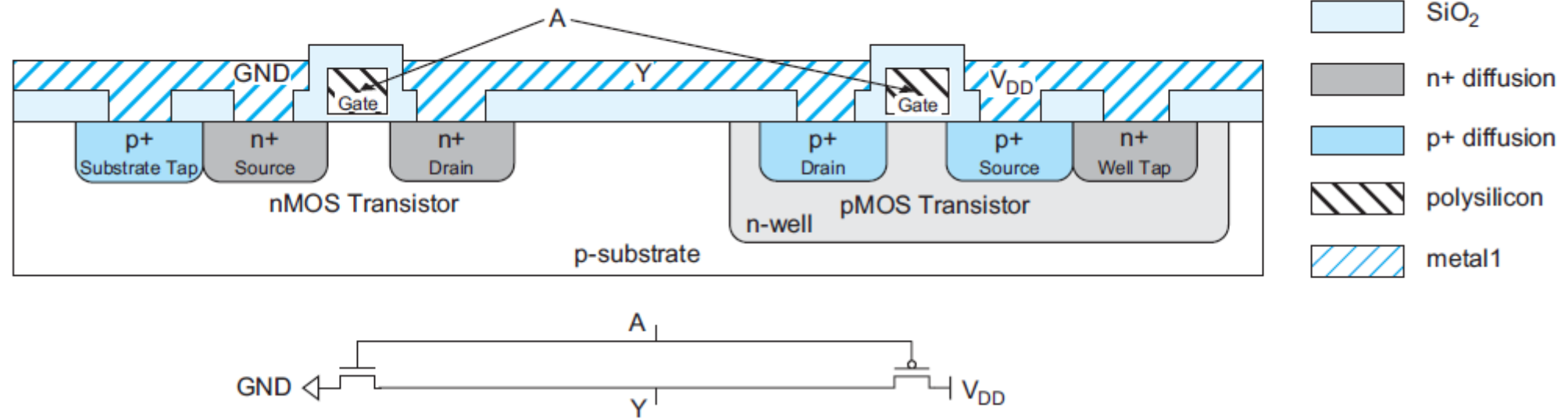


A	Y
0	1
1	0

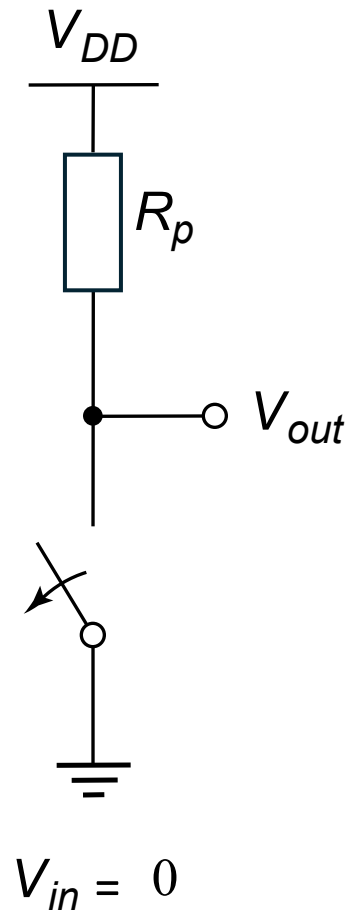
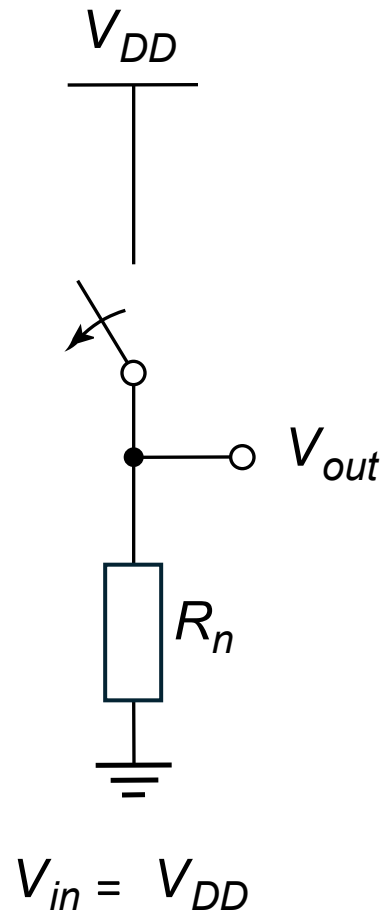
CMOS Inverter



CMOS Inverter

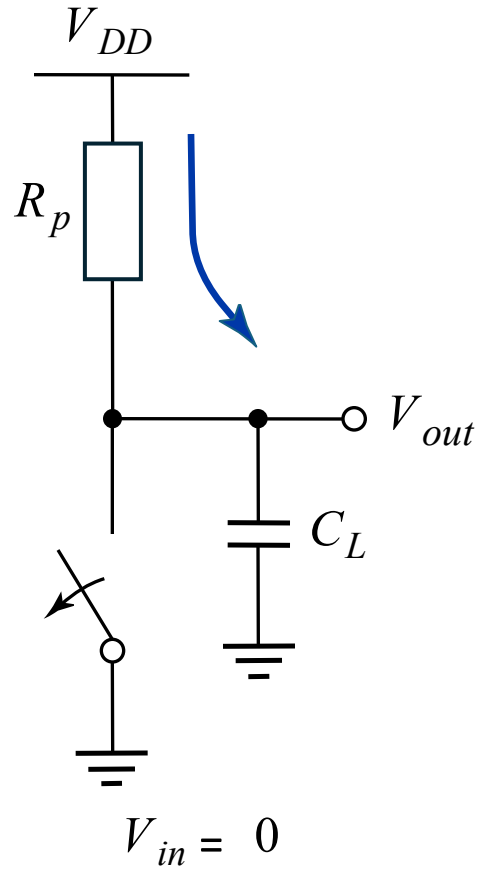


CMOS Inverter - First-Order DC Analysis

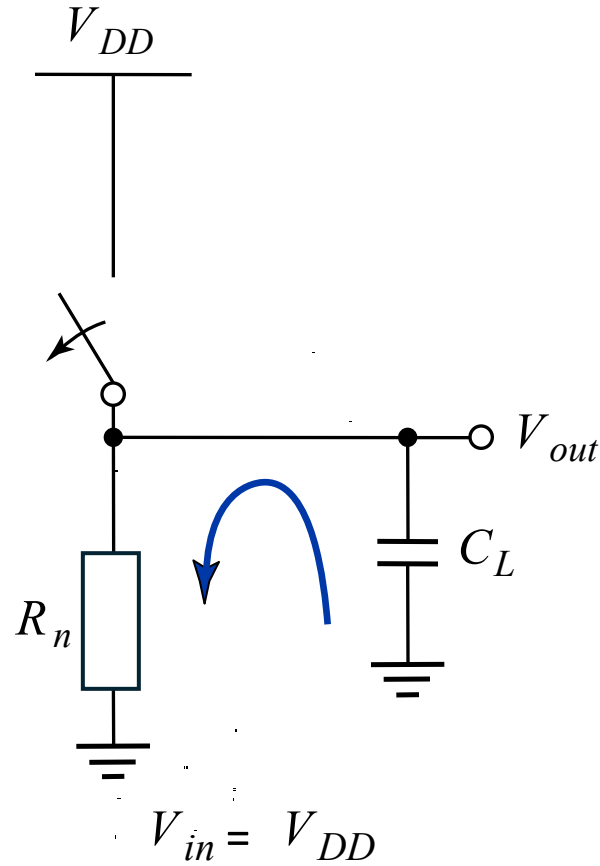


$$V_{OL} = 0$$
$$V_{OH} = V_{DD}$$

CMOS Inverter: Transient Response



(a) Low-to-high



(b) High-to-low

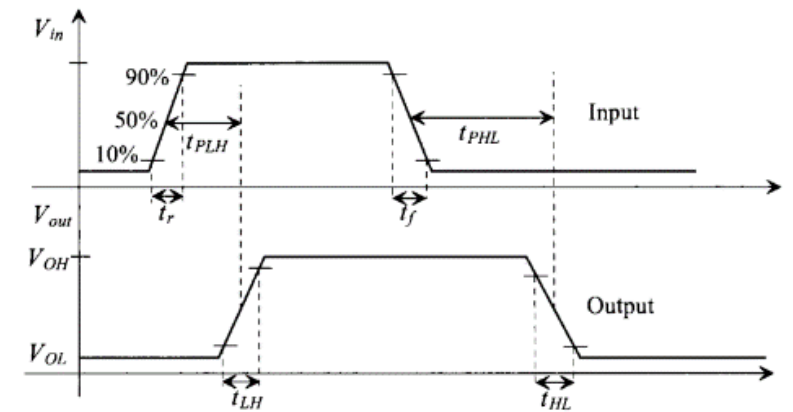
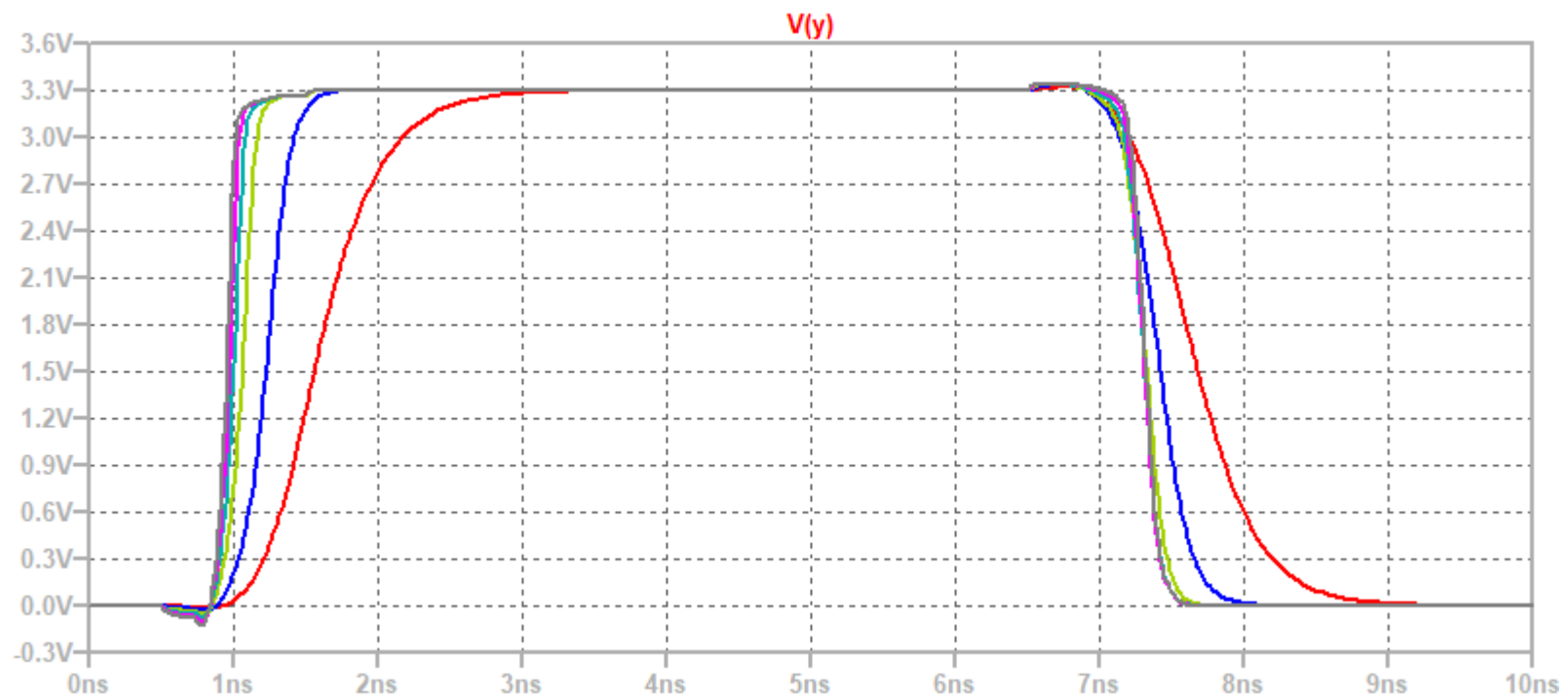
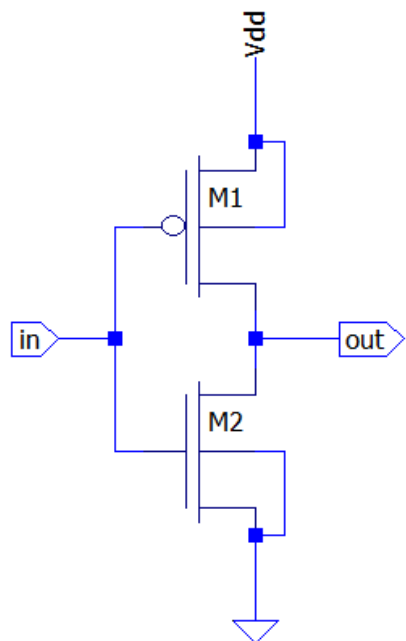


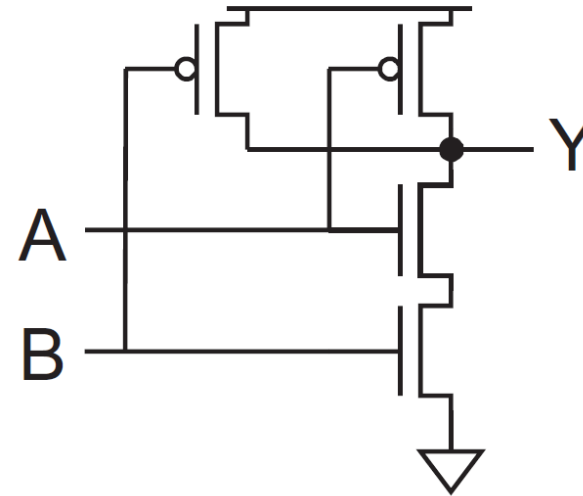
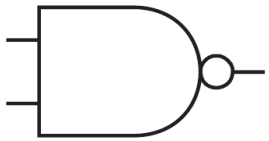
Figure 10.9 Definition of delays and transition times.

Инвертор – влияние на W върху бързодействието



CMOS Логически Елементи

NAND (NOT+AND)
И-НЕ



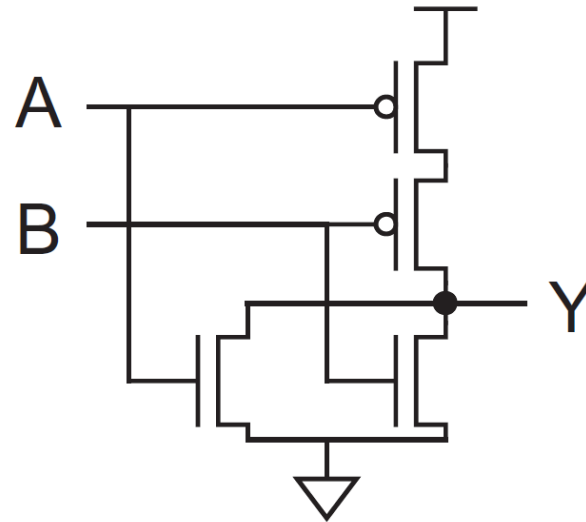
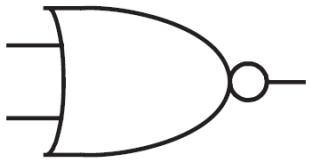
$$Y = \overline{A \cdot B}$$

$$Y = \neg(A \cdot B)$$

A	B	Pull-Down Network	Pull-Up Network	Y
0	0	OFF	ON	1
0	1	OFF	ON	1
1	0	OFF	ON	1
1	1	ON	OFF	0

CMOS Логически Елементи

NOR (NOT+OR)
ИЛИ-НЕ

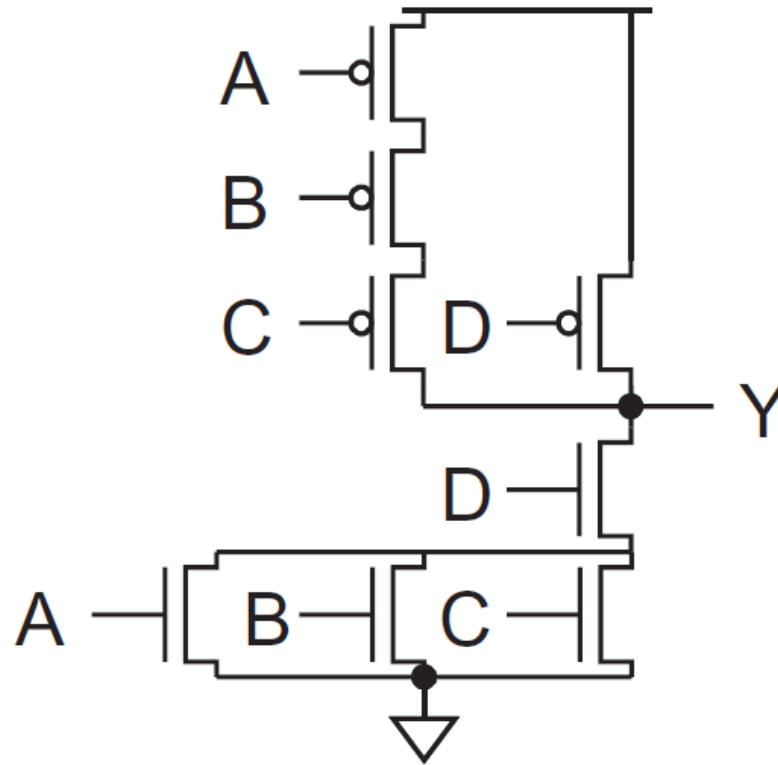


$$Y = \overline{A + B}$$

$$Y = \neg(A + B)$$

<i>A</i>	<i>B</i>	<i>Y</i>
0	0	1
0	1	0
1	0	0
1	1	0

CMOS Логически Елементи



$$Y = \overline{(A + B + C).D}$$